

### **General Description**

The WSD30L120ADN56 uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

#### **Features**

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- 100% E<sub>AS</sub> Guaranteed
- Green Device Available

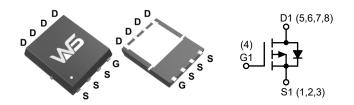
### **Product Summery**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub>
-30V	3.8mΩ	-120A

### **Applications**

- Lithium battery protection
- Wireless impact
- Mobile phone fast charging

### **DFN5X6-8L Pin Configuration**



### **Absolute Maximum Ratings** (T<sub>C</sub>=25°C, Unless Otherwise Noted)

Symbol	Parameter	Rating		
$V_{DS}$	Drain-Source Voltage	-30	V	
$V_{GS}$	Gate-Source Voltage ±20		V	
I <sub>D</sub> @T <sub>C</sub> =25°C	Continuous Drain Current, V <sub>GS</sub> @ -10V <sup>1</sup>	-120		
I <sub>D</sub> @T <sub>C</sub> =70°C	Continuous Drain Current, V <sub>GS</sub> @ -10V <sup>1</sup>	-65	A	
I <sub>DM</sub>	Pulse Drain Current <sup>2</sup>	-360		
E <sub>AS</sub>	Single Pulse Avalanche Energy <sup>3</sup>	225	mJ	
I <sub>AS</sub>	Avalanche Current	-60	А	
P <sub>D</sub> @T <sub>C</sub> =25°C	Total Power Dissipation <sup>4</sup>	103	W	
T <sub>STG</sub>	Storage Temperature Range	-55 to 150	°C	
T <sub>J</sub>	Operating Junction Temperature Range	-55 to 150		

#### **Thermal Data**

Symbol Parameter		Rating	Units	
$R_{ heta JA}$	Thermal Resistance Junction-Ambient <sup>1</sup>	25	°C/W	
$R_{ heta JC}$	Thermal Resistance Junction-Case <sup>1</sup>	1.46		



## **Electrical Characteristics** (T<sub>J</sub>=25°C, Unless Otherwise Noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V , I <sub>D</sub> =-250μA	-30			V
В	Statio Dunin Source On Bosistanos	V <sub>GS</sub> =-10V , I <sub>D</sub> =-30A		3.8	5.0	0
R <sub>DS(ON)</sub>	Static Drain-Source On-Resistance	V <sub>GS</sub> =-4.5V , I <sub>D</sub> =-20A		5.8	8.2	mΩ
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>GS</sub> =V <sub>DS</sub> , I <sub>D</sub> =-250μA	-1.2	-1.5	-2.5	V
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =-30V , V <sub>GS</sub> =0V			-1.0	μA
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =±20V , V <sub>DS</sub> =0V			±100	nA
$Q_g$	Total Gate Charge	V <sub>DS</sub> =-15V , I <sub>D</sub> =-30A ,		42		
$Q_{gs}$	Gate-Source Charge			9		nC
$Q_{gd}$	Gate-Drain Charge	V <sub>GS</sub> =-10V		12		
T <sub>d(on)</sub>	Turn-On Delay Time			15		
Tr	Turn-On Rise Time	V <sub>DD</sub> =-15V , I <sub>D</sub> =-30A ,		16		
$T_{d(off)}$	Turn-Off Delay Time	$V_{GS}$ =-10V , $R_{GEN}$ =2.5 $\Omega$		69		ns
T <sub>f</sub>	Turn-Off Fall Time			27		
C <sub>iss</sub>	Input Capacitance			9400		
C <sub>oss</sub>	Output Capacitance	$V_{DS}$ =-15V , $V_{GS}$ =0V , $f$ =1.0MHz		1000		pF
C <sub>rss</sub>	Reverse Transfer Capacitance			767		

### **Diode Characteristics**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
I <sub>S</sub>	Maximum Continuous Drain to Source Diode Forward Current				-90	^
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode Forward Current				-360	A
$V_{SD}$	Diode Forward Voltage V <sub>GS</sub> =0V , I <sub>S</sub> =-30A			-0.8	-1.2	V

#### Note:

- 1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.
- 2. The data tested by pulsed, pulse width. The  $\,{\rm E}_{\rm AS}\,$  data shows Max. rating.
- 3. The E\_{AS} condition: T\_J=25°C, V\_DD=-24V, V\_GS=-10V, R\_G=7\Omega, L=0.1mH, I\_{AS}=-60A
- 4. The power dissipation is limited by 150  $^{\circ}$ C junction temperature.
- 5. The data is theoretically the same as  $I_D$  and  $I_{DM}$ , in real applications, should be limited by total power dissipation.



## **Typical Characteristics**

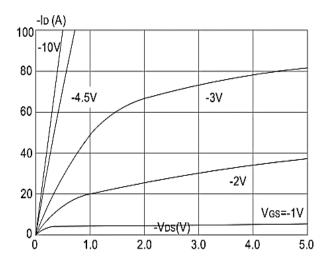


Figure1: Output Characteristics

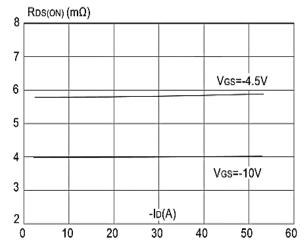


Figure 3:On-resistance vs. Drain Current

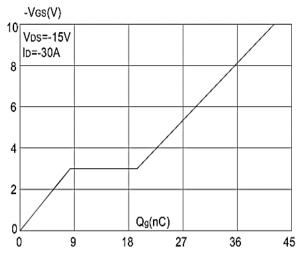
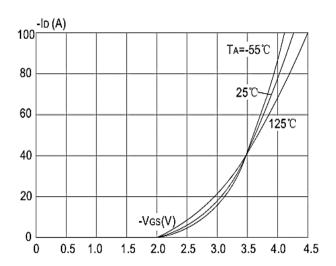
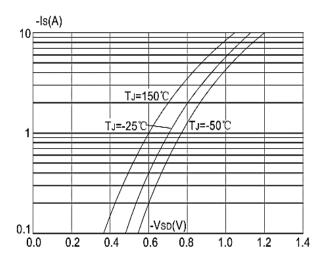


Figure 5: Gate Charge Characteristics



**Figure 2: Typical Transfer Characteristics** 



**Figure 4: Body Diode Characteristics** 

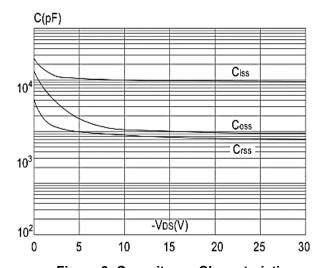


Figure 6: Capacitance Characteristics





### **Typical Characteristics (Cont.)**

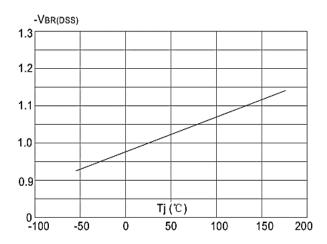


Figure 7: Normalized Breakdown Voltage vs. Junction Temperature

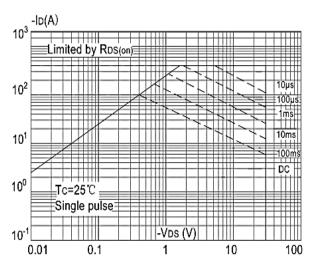


Figure 9: Maximum Safe Operating Area

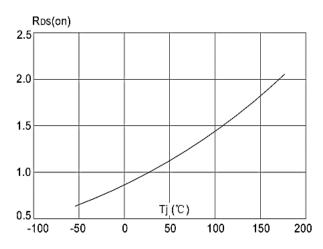


Figure 8: Normalized on Resistance vs. Junction Temperature

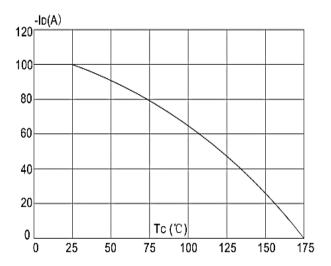


Figure 10: Maximum Continuous Drain Current vs. Case Temperature

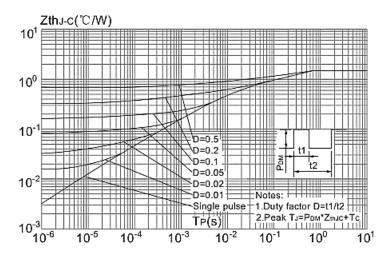
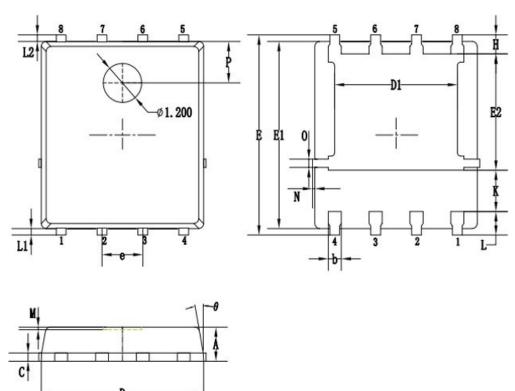


Figure.11: Maximum Effective Transient Thermal Impedance, Junction-to-Case

# **Packaging information**



SYMBOLS	MILLIMETERS		
	MIN.	NOM.	MAX.
Α	0.90	1.05	1.20
b	0.35	0.40	0.50
С	0.20	0.25	0.35
D	4.90	5.05	5.20
D1	3.72	3.82	3.92
E	6.00	6.15	6.30
E1	5.60	5.75	5.90
E2	3.47	3.57	3.67
е	1.27 BSC.		
Н	0.48	0.58	0.68
К	1.17	1.27	1.37
L	0.64	0.74	0.84
L1/L2		0.20 REF.	
θ	8°	10°	12°
М	0.08 REF.		
N	0	-	0.15
0	0.25 REF.		
Р	1.28 REF.		



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